

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
co) (60mΩ @ V _{GS} = -10V	-4.1A
-60V	80mΩ @ V _{GS} = -4.5V	-3.6A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC converters
- Motors

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMPH6051SSDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.
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https://www.diodes.com/quality/product-definitions/

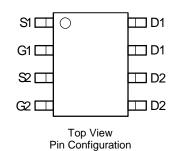
Mechanical Data

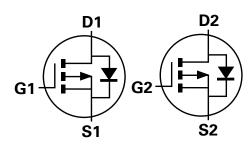
- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.074 grams (Approximate)



SO-8

Top View





Equivalent Circuit

Ordering Information (Note 4)

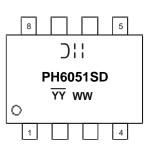
Orderable Part Number	Packaga	Packing		
	Package	Qty.	Carrier	
DMPH6051SSDQ-13	SO-8	2,500	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	-60	V	
Gate-Source Voltage			±20	V
Continuous Drain Current (Note 5) VGs = -10V	T _A = +25°C T _A = +100°C	١D	-4.1 -2.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	-30	А	
Maximum Continuous Body Diode Forward Current (Note 5)	Is	-4.1	А	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)	lsм	-30	А	
Avalanche Current, L = 0.1mH	las	-27.4	А	
Avalanche Energy, L = 0.1mH	E _{AS}	37.5	mJ	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic			Value	Units
Total Power Dissipation (Note 6)		PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	86	°C/W
Total Power Dissipation (Note 5)		PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	76	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

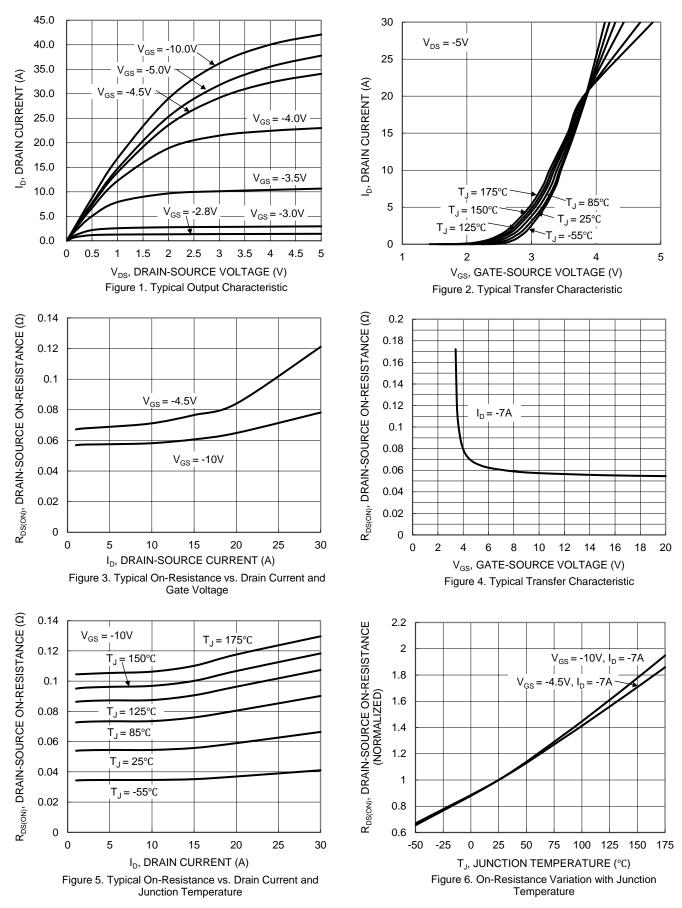
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			•			·	
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	-1	μA	V _{DS} = -60V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(th)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserve	_	46	60		Vgs = -10V, ID = -7A	
Static Drain-Source On-Resistance	RDS(ON)	—	58	80	mΩ	V _{GS} = -4.5V, I _D = -7A	
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	2079	—	pF		
Output Capacitance	Coss	—	95	_	pF	V _{DS} = -30V, V _{GS} = 0V f = 1MHz	
Reverse Transfer Capacitance	Crss	_	78	_	pF		
Gate Resistance	Rg	_	3.4	_	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	17	_	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	—	36	_	nC	Vps = -30V. lp = -5A	
Gate-Source Charge	Qgs	_	5.7	_	nC	VDS – -30V, ID – -5A	
Gate-Drain Charge	Q _{gd}	_	6.7	_	nC		
Turn-On Delay Time	td(on)	_	6.2	_	ns		
Turn-On Rise Time	t _R	_	22	_	ns	V _{DD} = -30V, V _{GS} = -10V	
Turn-Off Delay Time	tD(OFF)	_	39	_	ns	$R_g = 3\Omega$, $I_D = -5A$	
Turn-Off Fall Time	tF	—	24.7	_	ns		
Body Diode Reverse-Recovery Time	trr	_	24.5	—	ns	I = - 5 A di/dt = 100 A/ma	
Body Diode Reverse-Recovery Charge	Qrr		23.4	_	nC	— I _F = -5A, di/dt = 100A/μs	

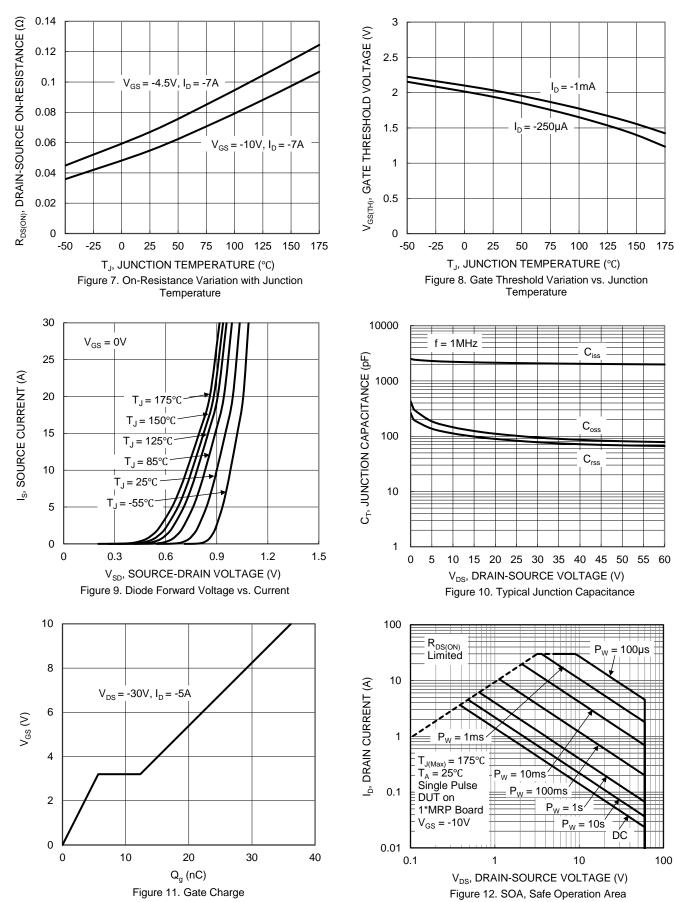
Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

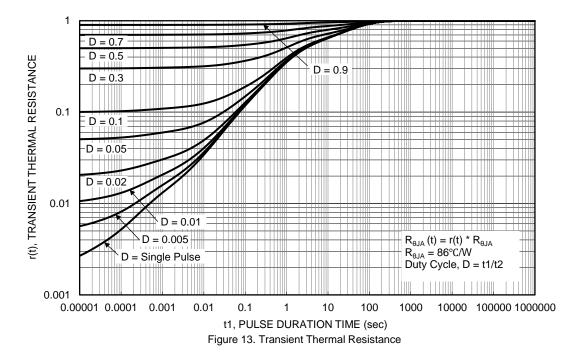








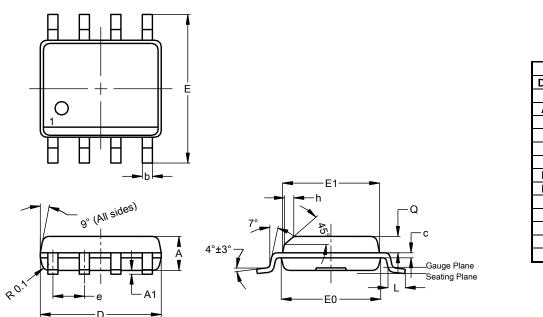






Package Outline Dimensions

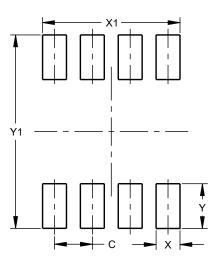
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8						
Dim	Min	Max	Тур			
Α	1.40	1.50	1.45			
A1	0.10	0.20	0.15			
b	0.30	0.50	0.40			
С	0.15	0.25	0.20			
D	4.85	4.95	4.90			
Е	5.90	6.10	6.00			
E1	3.80	3.90	3.85			
E0	3.85	3.95	3.90			
е			1.27			
h			0.35			
L	0.62	0.82	0.72			
q	0.60	0.70	0.65			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

SO-8

Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50



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